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Product data sheet

1. Product profile

1.1 General description

NPN/PNP transistor pair connected as push-pull driver in a SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

1.2 Features

- Switching transistors in push-pull configuration
- Application-optimized pinout
- Space-saving solution
- Internal connections to minimize layout effort
- Reduces component count

1.3 Applications

- MOSFET driver
- Power bipolar transistor driver
- Output current booster for operational amplifier

1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|------------------------------|--|------|-----|-----|------|
| Per transis | stor; for the PNP transistor | with negative pola | rity | | | |
| V _{CEO} | collector-emitter voltage | open base | - | - | 40 | V |
| I _C | collector current | | - | - | 0.6 | А |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | - | - | 1 | А |



2. Pinning information

| Table 2. | Pinning | | |
|----------|------------------|--------------------|----------------------|
| Pin | Description | Simplified outline | Symbol |
| 1 | base TR1, TR2 | | |
| 2 | collector TR2 | | |
| 3 | collector TR2 | 0 | |
| 4 | emitter TR1, TR2 | | |
| 5 | collector TR1 | | |
| 6 | collector TR1 | | 1 1 2 3 006aaa659 |

3. Ordering information

| Table 3. Order | Ordering information | | | | | |
|----------------|----------------------|--|---------|--|--|--|
| Type number | Package | | | | | |
| | Name | Description | Version | | | |
| PMD2001D | SC-74 | plastic surface-mounted package (TSOP6); 6 leads | SOT457 | | | |

4. Marking

| Table 4. Marking codes | 5 | |
|------------------------|--------------|--|
| Type number | Marking code | |
| PMD2001D | 9E | |

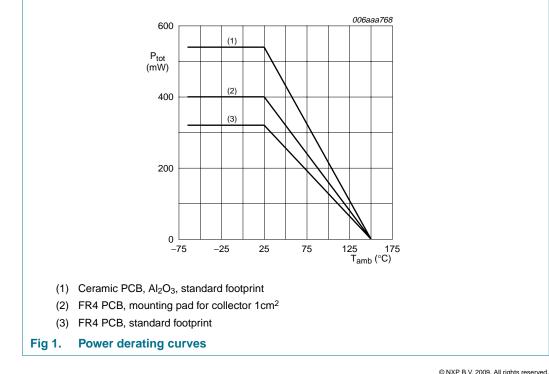
Limiting values 5.

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|--------------------------------|--|--------------|------|------|
| Per transis | stor; for the PNP transistor v | with negative polari | ty | | |
| V _{CBO} | collector-base voltage | open emitter | - | 40 | V |
| V _{CEO} | collector-emitter voltage | open base | - | 40 | V |
| I _C | collector current | | - | 0.6 | А |
| I _{CM} | peak collector current | single pulse; t _p ≤ 1 ms | - | 1 | A |
| I _{BM} | peak base current | | - | 0.1 | А |
| | | single pulse; $t_p \leq 1 ms$ | - | 0.2 | A |
| Per device |) | | | | |
| P _{tot} | total power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | <u>[1]</u> _ | 320 | mW |
| | | | [2] | 400 | mW |
| | | | [3] | 540 | mW |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -65 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1cm².

[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.



PMD2001D_2 **Product data sheet**

MOSFET driver

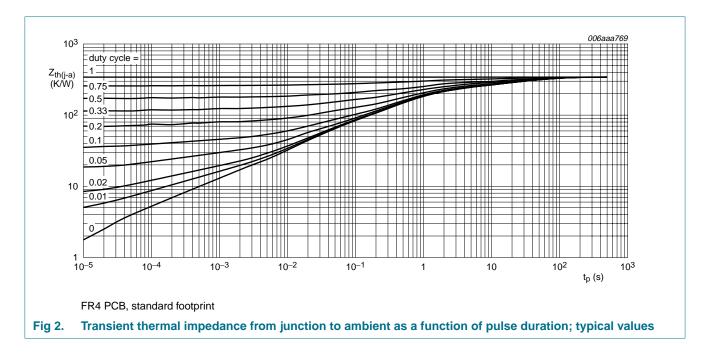
6. Thermal characteristics

| Table 6. | Thermal characteristics | | | | | |
|----------|-------------------------|-------------|--------------|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| ui(j-a) | thermal resistance from | in free air | <u>[1]</u> - | - | 390 | K/W |
| | junction to ambient | | [2] _ | - | 315 | K/W |
| | | | <u>[3]</u> _ | - | 230 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1cm².

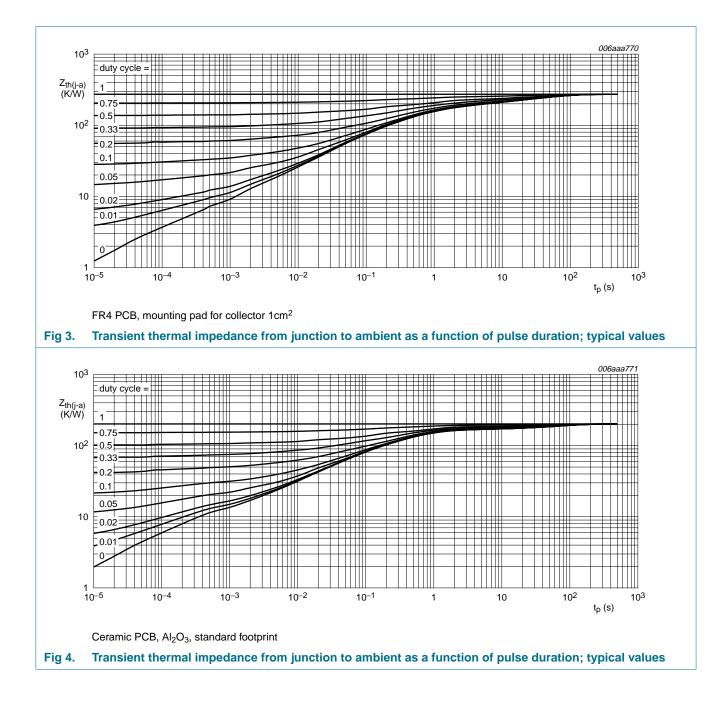
[3] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.





PMD2001D

MOSFET driver



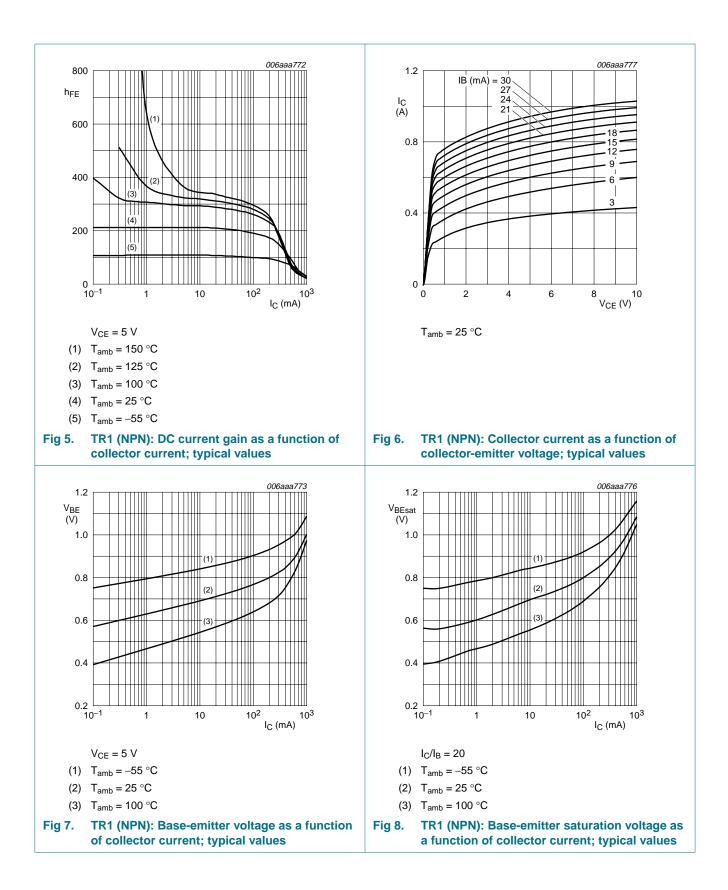
7. Characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|--------------------|------------------------|--|-----|-----|-------|------|------|
| Per NPN | I transistor | | | | | | |
| I _{CBO} | collector-base cut-off | $V_{CB} = 40 \text{ V}; I_E = 0 \text{ A}$ | | - | - | 10 | nA |
| | current | $\label{eq:VCB} \begin{array}{l} V_{CB} = 40 \; V; \; I_{E} = 0 \; A; \\ T_{j} = 150 \; ^{\circ}C \end{array}$ | | - | - | 10 | μA |
| h _{FE} | DC current gain | V_{CE} = 5 V; I_C = 1 mA | | 100 | 210 | - | |
| | | $V_{CE} = 5 \text{ V}; I_{C} = 200 \text{ mA}$ | | 100 | 170 | 300 | |
| | | $V_{CE} = 5 \text{ V}; I_{C} = 500 \text{ mA}$ | [1] | 50 | 100 | - | |
| V _{CEsat} | collector-emitter | $I_{C} = 200 \text{ mA}; I_{B} = 20 \text{ mA}$ | | - | 150 | 250 | mV |
| | saturation voltage | $I_{C} = 500 \text{ mA}; I_{B} = 50 \text{ mA}$ | [1] | - | 300 | 500 | mV |
| V _{BEsat} | base-emitter | $I_{C} = 200 \text{ mA}; I_{B} = 20 \text{ mA}$ | | - | 0.86 | 1 | V |
| | saturation voltage | $I_{C} = 500 \text{ mA}; I_{B} = 50 \text{ mA}$ | [1] | - | 0.95 | 1.1 | V |
| Per PNF | rtansistor | | | | | | |
| I _{CBO} | | $V_{CB} = -40$ V; $I_E = 0$ A | | - | - | -10 | nA |
| | current | $V_{CB} = -40 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$ | | - | - | -10 | μA |
| h _{FE} D | DC current gain | V_{CE} = -5 V; I_C = -1 mA | | 100 | 180 | - | |
| | | $V_{CE} = -5 \text{ V}; I_C = -200 \text{ mA}$ | | 80 | 125 | 300 | |
| | | V_{CE} = -5 V; I _C = -500 mA | [1] | 50 | 80 | - | |
| V _{CEsat} | collector-emitter | I_C = -200 mA; I_B = -20 mA | | - | -130 | -250 | mV |
| | saturation voltage | I_C = -500 mA; I_B = -50 mA | [1] | - | -280 | -500 | mV |
| V _{BEsat} | base-emitter | I_C = -200 mA; I_B = -20 mA | | - | -0.87 | -1 | V |
| | saturation voltage | $I_C = -500 \text{ mA}; I_B = -50 \text{ mA}$ | [1] | - | -0.98 | -1.1 | V |
| Per dev | ice | | | | | | |
| t _d | delay time | $I_{C} = 0.15 \text{ A}; V_{I} = 7.5 \text{ V}$ | | - | 3 | - | ns |
| t _r | rise time | | | - | 3 | - | ns |
| t _{on} | turn-on time | | | - | 6 | - | ns |
| t _s | storage time | | | - | 2 | - | ns |
| t _f | fall time | | | - | 3 | - | ns |
| t _{off} | turn-off time | | | - | 5 | - | ns |

[1] Pulse test: $t_p \leq 300~\mu s; \, \delta \leq 0.02$

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PMD2001D MOSFET driver

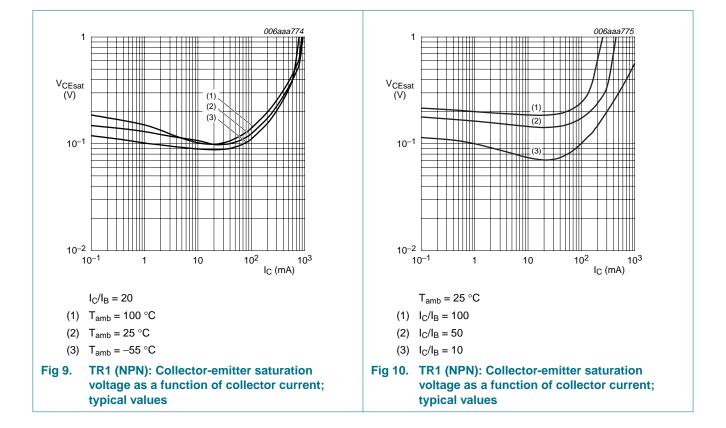


PMD2001D_2 Product data sheet

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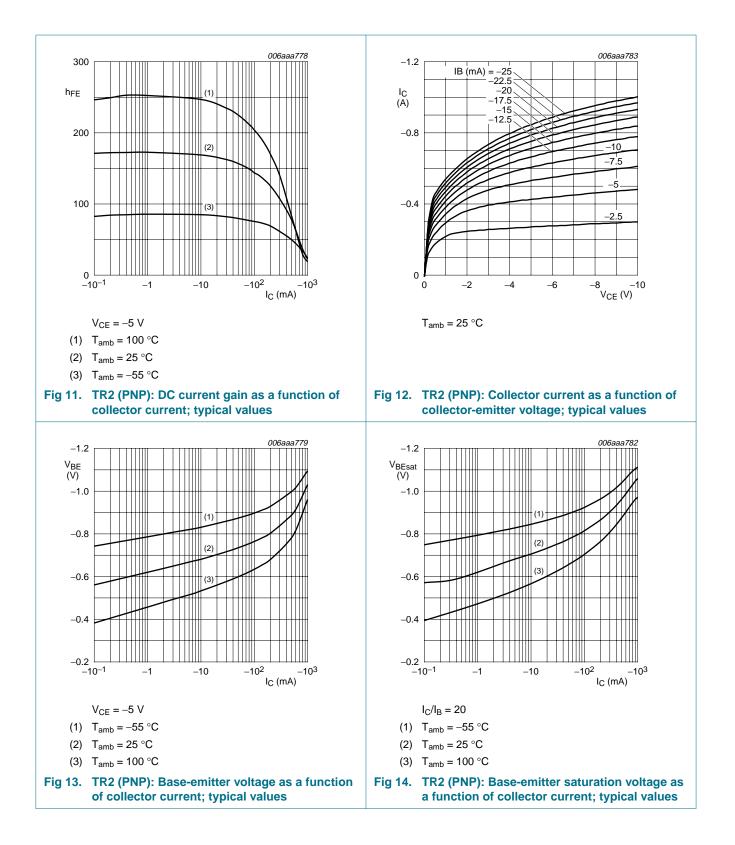
PMD2001D

MOSFET driver



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MOSFET driver

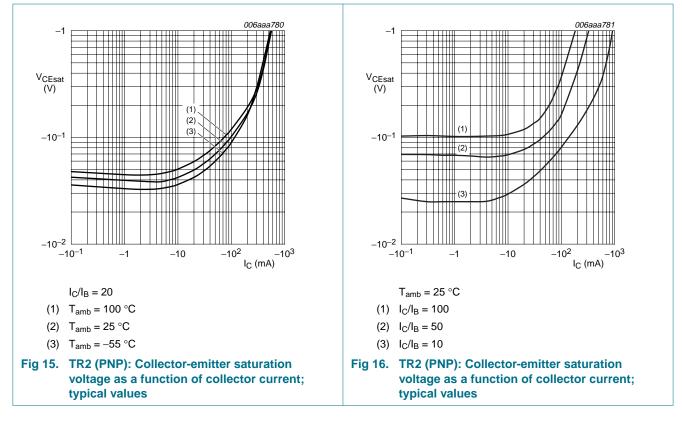


PMD2001D_2 Product data sheet

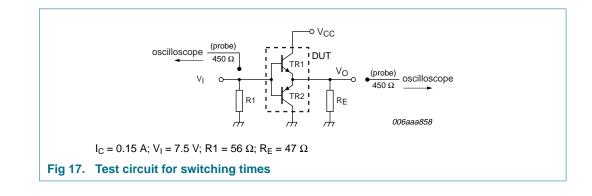
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PMD2001D

MOSFET driver

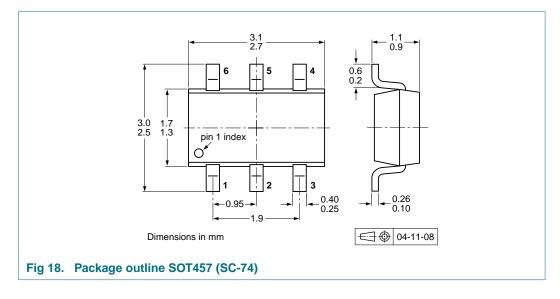


8. Test information



PMD2001D MOSFET driver

9. Package outline



10. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Type number Package Description | | Packing | g quantity |
|-------------|---------------------------------|------------------------------------|---------|------------|
| | | | 3000 | 10000 |
| PMD2001D | SOT457 | 4 mm pitch, 8 mm tape and reel; T1 | 2 -115 | -135 |
| | | 4 mm pitch, 8 mm tape and reel; T2 | 3 -125 | -165 |

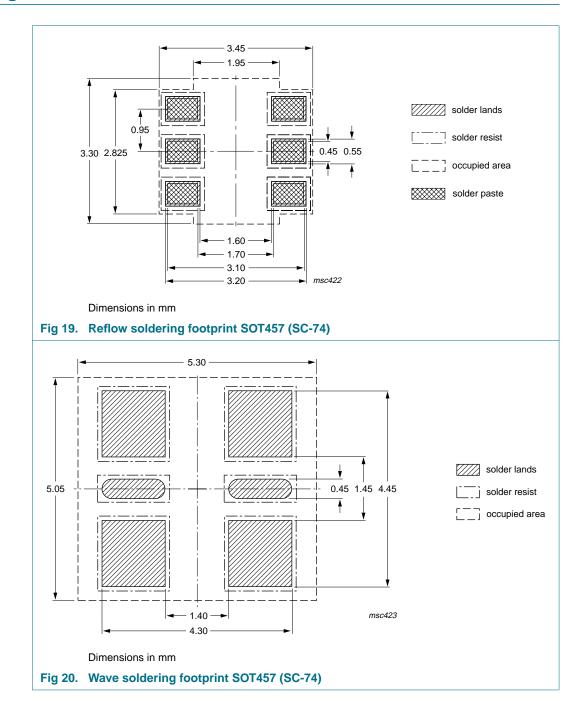
[1] For further information and the availability of packing methods, see <u>Section 14</u>.

[2] T1: normal taping

[3] T2: reverse taping

PMD2001D MOSFET driver

11. Soldering



12. Revision history

| Table 9. Revision his | story | | | |
|-----------------------|----------------------------------|--|---------------|------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| PMD2001D_2 | 20090828 | Product data sheet | - | PMD2001D_1 |
| Modifications: | | eet was changed to reflec w legal definitions and dis | | |
| | Figure 20 "V | Vave soldering footprint SC | <u> </u> | d |
| PMD2001D_1 | 20060925 | Product data sheet | - | - |

13. Legal information

13.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Product data sheet

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MOSFET driver

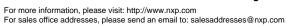
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